# Operational Amplifier, Zero-Drift, 10 $\mu$ V Offset, 0.07 $\mu$ V/°C

## NCS333A, NCV333A, NCS2333, NCV2333, NCS4333, NCV4333, NCS333

The NCS333/2333/4333 family of zero-drift op amps feature offset voltage as low as 10  $\mu$ V over the 1.8 V to 5.5 V supply voltage range. The zero-drift architecture reduces the offset drift to as low as 0.07  $\mu$ V/°C and enables high precision measurements over both time and temperature. This family has low power consumption over a wide dynamic range and is available in space saving packages. These features make it well suited for signal conditioning circuits in portable, industrial, automotive, medical and consumer markets.

#### Features

- Gain-Bandwidth Product:
  - 270 kHz (NCx2333)
  - 350 kHz (NCx333, NCx333A, NCx4333)
- Low Supply Current: 17 μA (typ at 3.3 V)
- Low Offset Voltage:
  - 10 μV max for NCS333, NCS333A
  - + 30 μV max for NCV333A, NCx2333 and NCx4333
- Low Offset Drift: 0.07  $\mu V/^{\circ}C$  max for NCS333/A
- Wide Supply Range: 1.8 V to 5.5 V
- Wide Temperature Range:  $-40^{\circ}$ C to  $+125^{\circ}$ C
- Rail-to-Rail Input and Output
- Available in Single, Dual and Quad Packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

#### Applications

- Automotive
- Battery Powered/ Portable Application
- Sensor Signal Conditioning
- Low Voltage Current Sensing
- Filter Circuits
- Bridge Circuits
- Medical Instrumentation



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SOT23-5 SN SUFFIX CASE 483 5 🕅

SC70-5 SQ SUFFIX CASE 419A



UDFN8 MU SUFFIX CASE 517AW MSOP-8 DM SUFFIX CASE 846A-02





SOIC-8 D SUFFIX CASE 751

SOIC-14 D SUFFIX CASE 751A



DT SUFFIX CASE 948G

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 2 of this data sheet.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 3 of this data sheet.

#### **DEVICE MARKING INFORMATION**

Single Channel Configuration NCS333, NCS333A, NCV333A



TSOP-5/SOT23-5 CASE 483



SC70-5 CASE 419A

Dual Channel Configuration NCS2333, NCV2333



UDFN8, 2x2, 0.5P CASE 517AW



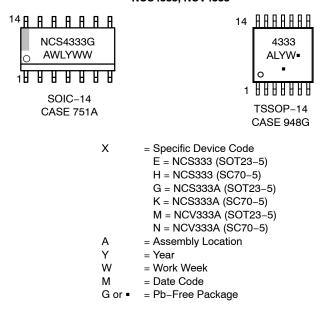


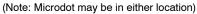
SOIC-8 CASE 751

#### Quad Channel Configuration NCS4333, NCV4333

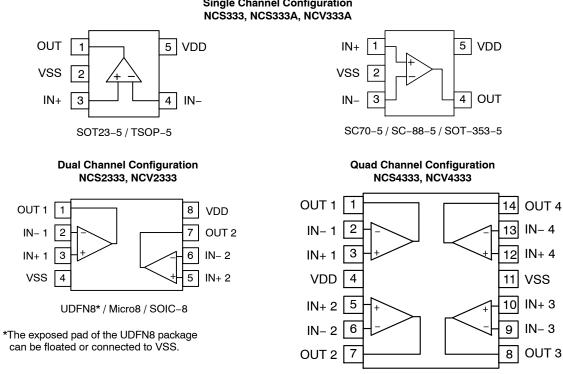
Micro8/MSOP8

CASE 846A-02





#### **PIN CONNECTIONS**



SOIC-14 / TSSOP-14

IN-4

IN+ 4

VSS

IN- 3

#### **ORDERING INFORMATION**

Channels	Device	Package	Shipping <sup>†</sup>
Single	NCS333SN2T1G	SOT23-5 / TSOP-5	3000 / Tape & Reel
	NCS333ASN2T1G		3000 / Tape & Reel
	NCS333SQ3T2G	SC70-5 / SC-88-5 / SOT-353-5	3000 / Tape & Reel
	NCS333ASQ3T2G		3000 / Tape & Reel
Dual	NCS2333MUTBG	UDFN8	3000 / Tape & Reel
	NCS2333DR2G	SOIC-8	3000 / Tape & Reel
	NCS2333DMR2G	MICRO-8	4000 / Tape & Reel
Quad	NCS4333DR2G	SOIC-14	2500 / Tape & Reel
	NCS4333DTBR2G (In Development*)	TSSOP-14	2500 / Tape & Reel

#### Automotive Qualified

Channels	Device	Package	Shipping <sup>†</sup>
Single	NCV333ASN2T1G	SOT23-5 / TSOP-5	3000 / Tape & Reel
	NCV333ASQ3T2G	SC70-5 / SC-88-5 / SOT-353-5	3000 / Tape & Reel
Dual	NCV2333DR2G	SOIC-8	3000 / Tape & Reel
	NCV2333DMR2G	MICRO-8	4000 / Tape & Reel
Quad	NCV4333DR2G	SOIC-14	2500 / Tape & Reel
	NCV4333DTBR2G (In Development*)	TSSOP-14	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*Contact local sales office for more information.

#### ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature, unless otherwise stated.

Parameter	Rating	Unit
Supply Voltage	7	V
INPUT AND OUTPUT PINS		-
Input Voltage (Note 1)	(VSS) – 0.3 to (VDD) + 0.3	V
Input Current (Note 1)	±10	mA
Output Short Circuit Current (Note 2)	Continuous	
TEMPERATURE		
Operating Temperature Range	-40 to +125	°C
Storage Temperature Range	-65 to +150	°C
Junction Temperature	+150	°C
ESD RATINGS (Note 3)		
Human Body Model (HBM)	±4000	V
Machine Model (MM)	±200	V
Charged Device Model (CDM)	±2000	V
OTHER RATINGS		
Latch-up Current (Note 4)	100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Level 1

1. Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3 V beyond the supply rails should be current limited to 10 mA or less

2. Short-circuit to ground.

MSL

 This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per JEDEC standard JS-001 (AEC-Q100-002) ESD Machine Model tested per JEDEC standard JESD22-A115 (AEC-Q100-003) ESD Charged Device Model tested per JEDEC standard JESD22-C101 (AEC-Q100-011)

- ESD Charged Device Model tested per JEDEC standard JESD22-C101 (/
- 4. Latch-up Current tested per JEDEC standard: JESD78.

#### THERMAL INFORMATION (Note 5)

Parameter	Symbol	Package	Value	Unit									
Thermal Resistance,	$\theta_{JA}$	SOT23–5 / TSOP5	290	°C/W									
Junction to Ambient		SC70-5 / SC-88-5 / SOT-353-5	425	1									
		Micro8 / MSOP8	298	1									
											SOIC-8	250	1
		UDFN8	228	1									
		SOIC-14	216	1									
		TSSOP-14	155										

5. As mounted on an 80x80x1.5 mm FR4 PCB with 650 mm<sup>2</sup> and 2 oz (0.07 mm) thick copper heat spreader. Following JEDEC JESD/EIA 51.1, 51.2, 51.3 test guidelines

#### **RECOMMENDED OPERATING CONDITIONS**

Parameter	Parameter			Unit
Supply Voltage (V <sub>DD</sub> – V <sub>SS</sub> )		VS	1.8 to 5.5	V
Specified Operating Temperature Range	NCS333	T <sub>A</sub>	-40 to 105	°C
NCx33	3A, NCx2333, NCx4333		-40 to 125	
Input Common Mode Voltage Range		VICMR	$V_{SS}$ –0.1 to $V_{DD}$ +0.1	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

**ELECTRICAL CHARACTERISTICS:**  $V_S = 1.8 V$  to 5.5 V At  $T_A = +25^{\circ}C$ ,  $R_L = 10 k\Omega$  connected to midsupply,  $V_{CM} = V_{OUT} =$  midsupply, unless otherwise noted. **Boldface** limits apply over the specified operating temperature range, guaranteed by characterization and/or design.

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
Offset Voltage	V <sub>OS</sub>	V <sub>S</sub> = +5 V	NCS333, NCS333A		3.5	10	μV
			NCV333A, NCx2333, NCx4333		6.0	30	
Offset Voltage Drift vs Temp	$\Delta V_{OS} / \Delta T$	NCS333,	NCS333A		0.03	0.07	μV/°C
		NCV333A	A, V <sub>S</sub> = 5 V		0.03	0.14	1
		NCx2333	8, V <sub>S</sub> = 5 V		0.04	0.07	1
		NCx4333	8, V <sub>S</sub> = 5 V		0.095	0.19	1
Offset Voltage Drift vs Supply	$\Delta V_{OS} / \Delta V_{S}$	NCS333, NCS333A	Full temperature range		0.32	5	μV/V
		NCV333A	T <sub>A</sub> = +25°C		0.40	5	1
			Full temperature range			8	1
		NCx2333, NCx4333	T <sub>A</sub> = +25°C		0.32	5	1
			Full temperature range			12.6	
Input Bias Current	$I_{\text{IB}}$ $T_{\text{A}}$ = +25°C NCS333, NCx333A	±60	±200	pА			
(Note 6)			NCx2333, NCx4333		±60	±400	1
		Full temper	rature range		±400		1
Input Offset Current	I <sub>OS</sub>	$T_A = +25^{\circ}C$	NCS333, NCx333A		±50	±400	pА
(Note 6)			NCx2333, NCx4333		±50	±800	1
Common Mode Rejection Ratio	CMRR	V <sub>S</sub> =	1.8 V		111		dB
(Note 7)		V <sub>S</sub> =	3.3 V		118		1
		V <sub>S</sub> = 5.0 V	NCS333, NCS333A, NCx2333, NCx4333	106	123		
			NCV333A	103	123		1
		V <sub>S</sub> =	5.5 V		127		1
Input Resistance	R <sub>IN</sub>	Diffe	rential		180		GΩ
		Commo	on Mode		90		1
Input Capacitance	C <sub>IN</sub>	NCS333	Differential		2.3		pF
			Common Mode		4.6		1
		NCx2333, NCx4333,	Differential		4.1		1
		NCx333A	Common Mode		7.9		1

#### **OUTPUT CHARACTERISTICS**

Open Loop Voltage Gain (Note 6)	A <sub>VOL</sub>	V <sub>SS</sub> + 100 mV < V <sub>O</sub> < V <sub>DD</sub> – 100 mV	106	145		dB
Open Loop Output Impedance	Z <sub>out-OL</sub>	f = UGBW, I <sub>O</sub> = 0 mA		300		Ω
Output Voltage High,	V <sub>OH</sub>	$T_A = +25^{\circ}C$		10	50	mV
Referenced to V <sub>DD</sub>		Full temperature range			70	
Output Voltage Low,	V <sub>OL</sub>	$T_A = +25^{\circ}C$		10	50	mV
Referenced to V <sub>SS</sub>		Full temperature range			70	

6. Guaranteed by characterization and/or design 7. Specified over the full common mode range:  $V_{SS} - 0.1 < V_{CM} < V_{DD} + 0.1$ 

#### **ELECTRICAL CHARACTERISTICS:** $V_S = 1.8 V$ to 5.5 V

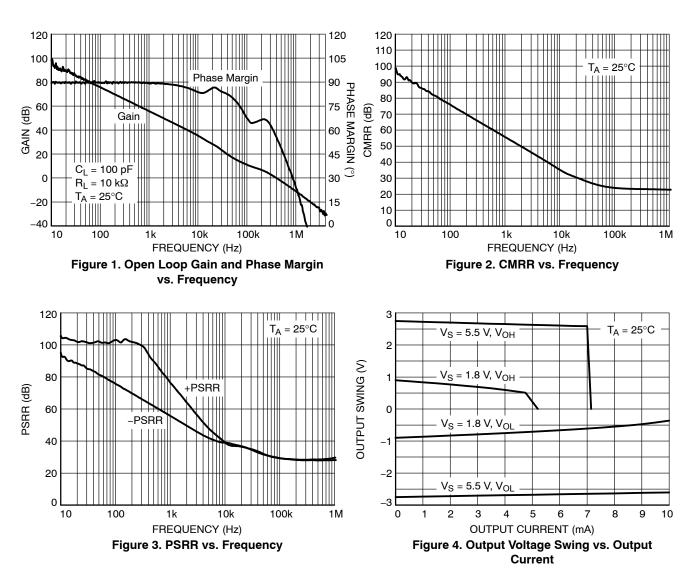
At  $T_A = +25^{\circ}C$ ,  $R_L = 10 \text{ k}\Omega$  connected to midsupply,  $V_{CM} = V_{OUT}$  = midsupply, unless otherwise noted.

Boldface limits apply over the specified operating temperature range, guaranteed by characterization and/or design.

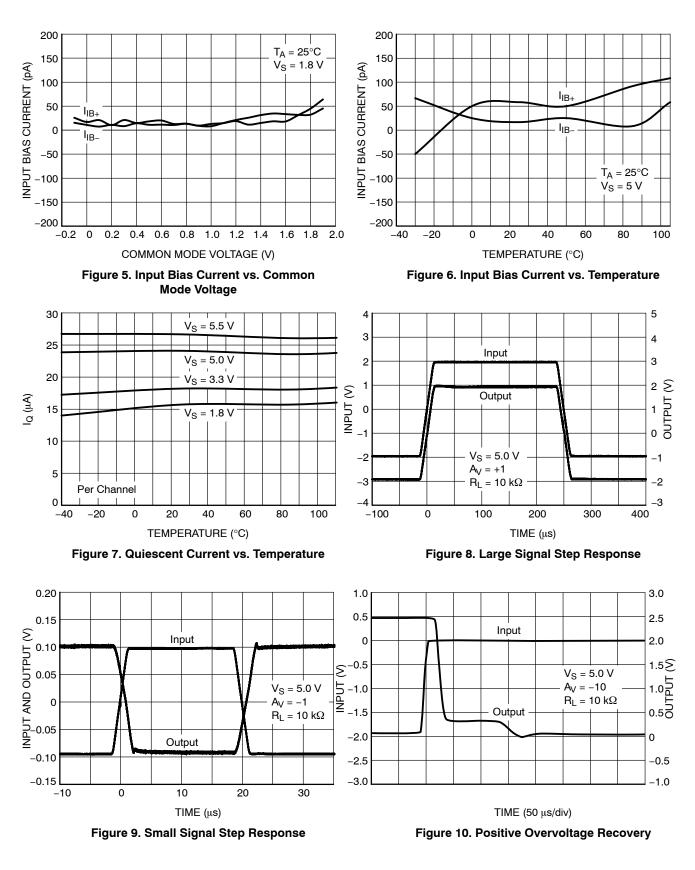
Parameter	Symbol	Cond	itions	Min	Тур	Max	Unit
OUTPUT CHARACTERISTICS	•	•			-		
Output Current Capability	Ι <sub>Ο</sub>	Sinking Current	NCS333		25		mA
			NCx333A, NCx2333, NCx4333		11		
		Sourcing	g Current		5.0		
Capacitive Load Drive	CL			S	ee Figure	13	
NOISE PERFORMANCE							
Voltage Noise Density	e <sub>N</sub>	f <sub>IN</sub> =	1 kHz		62		nV / $\sqrt{Hz}$
Voltage Noise	e <sub>P-P</sub>	f <sub>IN</sub> = 0.1 H	lz to 10 Hz		1.1		$\mu V_{PP}$
		f <sub>IN</sub> = 0.01	Hz to 1 Hz		0.5		
Current Noise Density	i <sub>N</sub>	f <sub>IN</sub> =	10 Hz		350		$fA / \sqrt{Hz}$
Channel Separation		NCx2333,	NCx4333		135		dB
DYNAMIC PERFORMANCE							
Gain Bandwidth Product	duct GBWP	VP C <sub>L</sub> = 100 pF	NCS333, NCx333A, NCx4333		350		kHz
			NCx2333		270		
Gain Margin	A <sub>M</sub>	C <sub>L</sub> = 1	00 pF		18		dB
Phase Margin	\$	C <sub>L</sub> = 1	00 pF		55		0
Slew Rate	SR	G =	: +1		0.15		V/μs
POWER SUPPLY							
Power Supply Rejection Ratio	PSRR	NCS333, NCS333A	Full temperature range	106	130		dB
		NCx2333, NCx4333,	$T_A = +25^{\circ}C$	106	130		
		NCV333A	Full temperature range	98			
Turn-on Time	t <sub>ON</sub>	V <sub>S</sub> =	= 5 V		100		μs
Quiescent Current	ا <sub>Q</sub>	NCS333, NCS333A,	$1.8 \text{ V} \le \text{V}_{S} \le 3.3 \text{ V}$		17	25	μΑ
(Note 8)		NCx2333, NCx4333				27	
			$3.3 \text{ V} < \text{V}_{\text{S}} \le 5.5 \text{ V}$		21	33	1
						35	
		NCV333A	$1.8~V \leq V_S \leq 3.3~V$		20	30	0
						35	
			$3.3 \text{ V} < \text{V}_{\text{S}} \le 5.5 \text{ V}$		28	40	
						45	]

8. No load, per channel

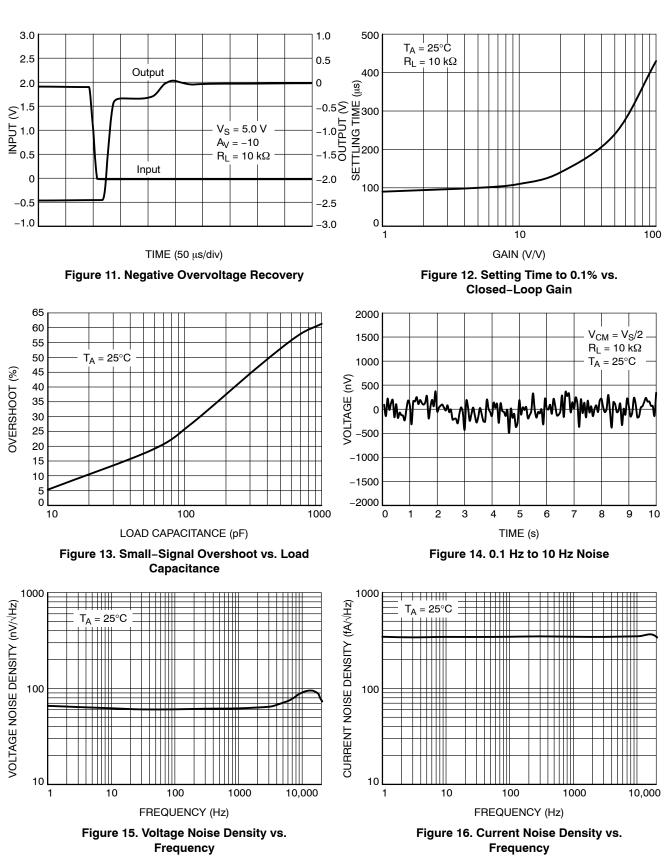
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**

#### **APPLICATIONS INFORMATION**

#### **OVERVIEW**

The NCS333, NCS333A, NCS2333, and NCS4333 precision op amps provide low offset voltage and zero drift over temperature. The input common mode voltage range extends 100 mV beyond the supply rails to allow for sensing near ground or VDD. These features make the NCS333 series well–suited for applications where precision is required, such as current sensing and interfacing with sensors.

NCS333 series of precision op amps uses a chopper-stabilized architecture, which provides the advantage of minimizing offset voltage drift over temperature and time. The simplified block diagram is shown in Figure 17. Unlike the classical chopper architecture, the chopper stabilized architecture has two signal paths.

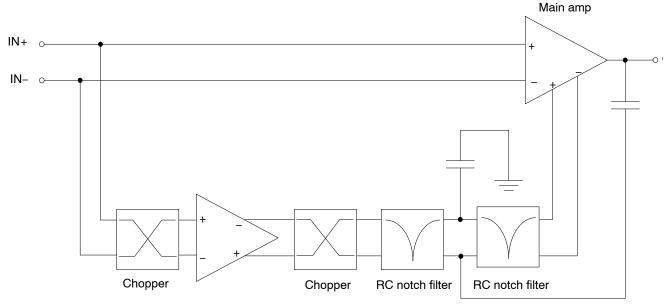


Figure 17. Simplified NCS333 Block Diagram

In Figure 17, the lower signal path is where the chopper samples the input offset voltage, which is then used to correct the offset at the output. The offset correction occurs at a frequency of 125 kHz. The chopper-stabilized architecture is optimized for best performance at frequencies up to the related Nyquist frequency (1/2 of the)offset correction frequency). As the signal frequency exceeds the Nyquist frequency, 62.5 kHz, aliasing may occur at the output. This is an inherent limitation of all chopper and chopper-stabilized architectures. Nevertheless, the NCS333 op amps have minimal aliasing up to 125 kHz and low aliasing up to 190 kHz when compared to competitor parts from other manufacturers. ON Semiconductor's patented approach utilizes two

cascaded, symmetrical, RC notch filters tuned to the chopper frequency and its fifth harmonic to reduce aliasing effects.

The chopper–stabilized architecture also benefits from the feed–forward path, which is shown as the upper signal path of the block diagram in Figure 17. This is the high speed signal path that extends the gain bandwidth up to 350 kHz. Not only does this help retain high frequency components of the input signal, but it also improves the loop gain at low frequencies. This is especially useful for low–side current sensing and sensor interface applications where the signal is low frequency and the differential voltage is relatively small.

#### **APPLICATION CIRCUITS**

#### Low-Side Current Sensing

Low-side current sensing is used to monitor the current through a load. This method can be used to detect over-current conditions and is often used in feedback control, as shown in Figure 18. A sense resistor is placed in series with the load to ground. Typically, the value of the sense resistor is less than 100 m $\Omega$  to reduce power loss across the resistor. The op amp amplifies the voltage drop across the sense resistor with a gain set by external resistors R1, R2, R3, and R4 (where R1 = R2, R3 = R4). Precision resistors are required for high accuracy, and the gain is set to utilize the full scale of the ADC for the highest resolution.

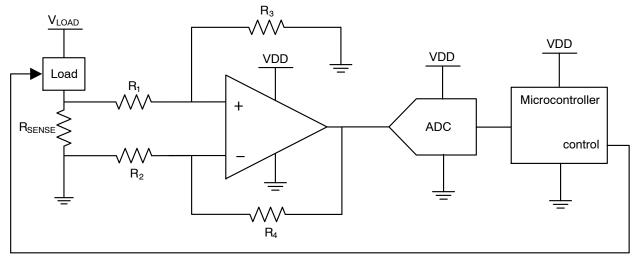


Figure 18. Low-Side Current Sensing

#### **Differential Amplifier for Bridged Circuits**

Sensors to measure strain, pressure, and temperature are often configured in a Wheatstone bridge circuit as shown in Figure 19. In the measurement, the voltage change that is produced is relatively small and needs to be amplified before going into an ADC. Precision amplifiers are recommended in these types of applications due to their high gain, low noise, and low offset voltage.

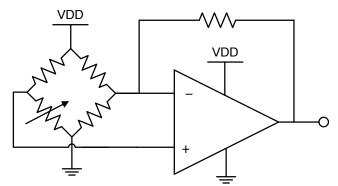


Figure 19. Bridge Circuit Amplification

#### **EMI Susceptibility and Input Filtering**

Op amps have varying amounts of EMI susceptibility. Semiconductor junctions can pick up and rectify EMI signals, creating an EMI-induced voltage offset at the output, adding another component to the total error. Input pins are the most sensitive to EMI. The NCS333 op amp family integrates low-pass filters to decrease sensitivity to EMI.

#### **General Layout Guidelines**

To ensure optimum device performance, it is important to follow good PCB design practices. Place 0.1  $\mu$ F decoupling capacitors as close as possible to the supply pins. Keep traces short, utilize a ground plane, choose surface-mount components, and place components as close as possible to the device pins. These techniques will reduce susceptibility to electromagnetic interference (EMI). Thermoelectric effects can create an additional temperature dependent offset voltage at the input pins. To reduce these effects, use metals with low thermoelectric-coefficients and prevent temperature gradients from heat sources or cooling fans.

#### **UDFN8 Package Guidelines**

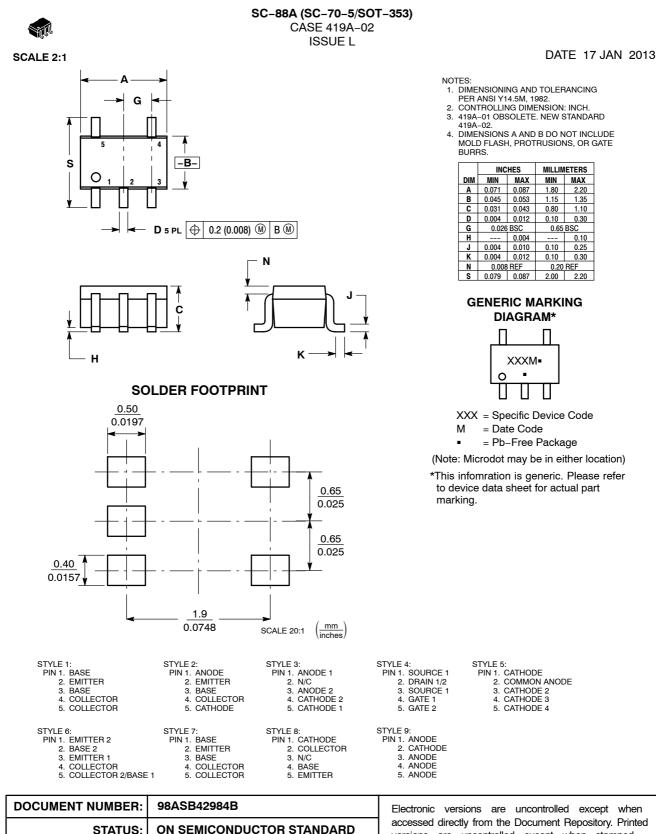
The UDFN8 package has an exposed leadframe die pad on the underside of the package. This pad should be soldered to the PCB, as shown in the recommended soldering footprint in the Package Dimensions section of this datasheet. The center pad can be electrically connected to VSS or it may be left floating. When connected to VSS, the center pad acts as a heat sink, improving the thermal resistance of the part.

STATUS:

SC-88A (SC-70-5/SOT-353)

**NEW STANDARD: DESCRIPTION:** 



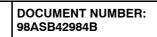


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С	CONVERTED FROM PAPER DOCUMENT TO ELECTRONIC. REQ. BY N LAFEB- RE.	20 JUN 1998
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F	DELETED DIMENSION V, WAS 0.3-0.44MM/0.012-0.016IN. REQ. BY G. KWONG.	14 JUN 2001
G	ADDED STYLE 8, REQ. BY S. CHANG; ADDED STYLE 9, REQ. BY S. BACHMAN; ADDED NOTE 4, REQ. BY S. RIGGS	25 JUN 2003
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J	CHANGED TITLE DESCRIPTION. REQ. BY B. LOFTS.	31 AUG 2005
К	CORRECTED TITLE AND DESCRIPTION TO SC-88A (SC-70-5/SOT-353). COR- RECTED MARKING DIAGRAM. REQ. BY D. TRUHITTE.	13 JUL 2010
L	ADDED SOLDER FOOTPRINT. REQ. BY I. MARIANO.	17 JAN 2013

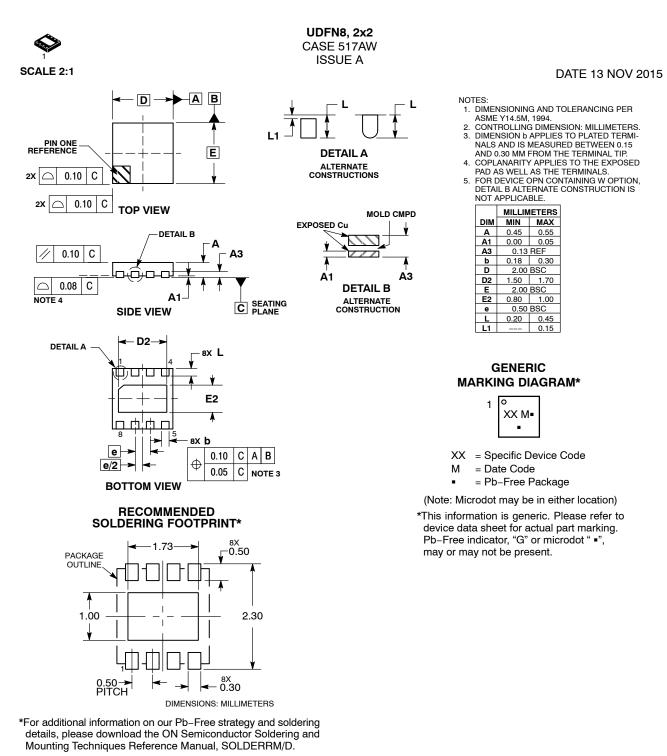
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#### SOIC-8 NB CASE 751-07 ISSUE AK

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER EMITTER 5. BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: CATHODE 1 PIN 1. 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: PIN 1. GROUND BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC COMMON CATHODE/VCC 3 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 COMMON ANODE/GND 8. STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. 4. DRAIN, #2 GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 DRAIN 1 7. 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. LINE 1 OUT 8. STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. SOURCE SOURCE 6. SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: ANODE ANODE PIN 1. 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 3. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. 4. GATE 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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SOURCE 1/DRAIN 2

7.

8. GATE 1

7.

8

rights of others

COLLECTOR, #1

COLLECTOR, #1





\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### SOIC-14 CASE 751A-03 ISSUE L

#### DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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